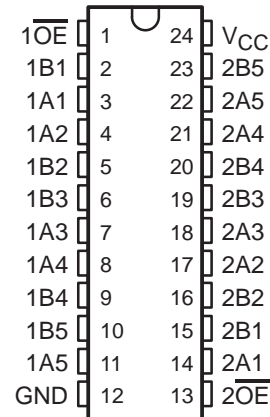


SN74CBTS3384
10-BIT FET BUS SWITCH
WITH SCHOTTKY DIODE CLAMPING
 SCDS024H – MAY 1995 – REVISED JULY 1999

- Functionally Equivalent to QS3384 and QS3L384
- 5- Ω Switch Connection Between Two Ports
- TTL-Compatible Input Levels
- Package Options Include Plastic Small-Outline (DW), Shrink Small-Outline (DB, DBQ), Thin Very Small-Outline (DGV), and Thin Shrink Small-Outline (PW) Packages

DB, DBQ, DGV, DW, OR PW PACKAGE
 (TOP VIEW)



description

The SN74CBTS3384 provides ten bits of high-speed TTL-compatible bus switching with Schottky diodes on the I/Os to clamp undershoot. The low on-state resistance of the switch allows connections to be made with minimal propagation delay.

The device is organized as two 5-bit bus switches with separate output-enable (\overline{OE}) inputs. When \overline{OE} is low, the switch is on and port A is connected to port B. When \overline{OE} is high, the switch is open and a high-impedance state exists between the two ports.

The SN74CBTS3384 is characterized for operation from -40°C to 85°C .

FUNCTION TABLE
 (each 5-bit bus switch)

INPUTS		INPUTS/OUTPUTS	
$\overline{1OE}$	$\overline{2OE}$	1B1–1B5	2B1–2B5
L	L	1A1–1A5	2A1–2A5
L	H	1A1–1A5	Z
H	L	Z	2A1–2A5
H	H	Z	Z



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**TEXAS
INSTRUMENTS**

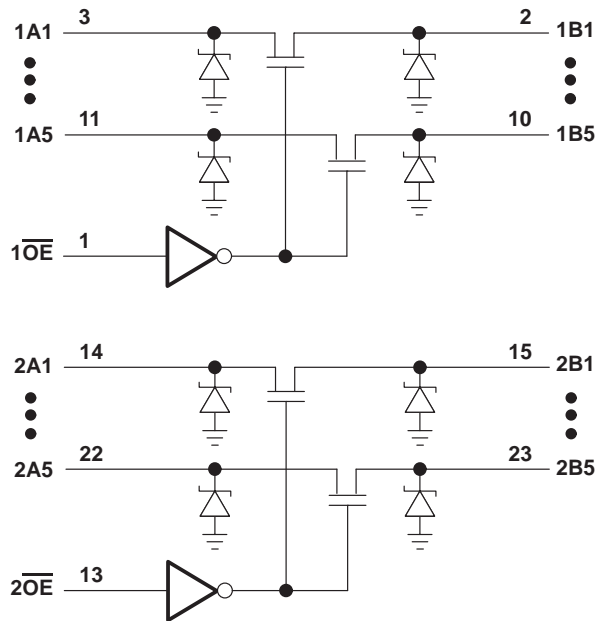
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logic diagram (positive logic)



absolute maximum ratings over operating free-air temperature range (unless otherwise noted)†

Supply voltage range, V_{CC}	−0.5 V to 7 V
Input voltage range, V_I (see Note 1)	−0.5 V to 7 V
Continuous channel current	128 mA
Input clamp current, I_{IK} ($V_{I/O} < 0$)	−50 mA
Package thermal impedance, θ_{JA} (see Note 2):	
DB package	104°C/W
DBQ package	113°C/W
DGV package	139°C/W
DW package	81°C/W
PW package	120°C/W
Storage temperature range, T_{stg}	−65°C to 150°C

† Stresses beyond those listed under “absolute maximum ratings” may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under “recommended operating conditions” is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

NOTES: 1. The input and output negative-voltage ratings may be exceeded if the input and output clamp-current ratings are observed.
2. The package thermal impedance is calculated in accordance with JESD 51.

recommended operating conditions (see Note 3)

	MIN	MAX	UNIT
V_{CC} Supply voltage	4	5.5	V
V_{IH} High-level control input voltage	2		V
V_{IL} Low-level control input voltage		0.8	V
T_A Operating free-air temperature	−40	85	°C

NOTE 3: All unused control inputs of the device must be held at V_{CC} or GND to ensure proper device operation. Refer to the TI application report, *Implications of Slow or Floating CMOS Inputs*, literature number SCBA004.

electrical characteristics over recommended operating free-air temperature range (unless otherwise noted)

PARAMETER		TEST CONDITIONS		MIN	TYP†	MAX	UNIT
V_{IK}		$V_{CC} = 4.5\text{ V}$,	$I_I = -18\text{ mA}$			-0.6	V
I_I	I_{IL}	$V_{CC} = 5.5\text{ V}$,	$V_I = \text{GND}$			-1	μA
	I_{IH}	$V_{CC} = 5.5\text{ V}$,	$V_I = 5.5\text{ V}$			150	
I_{CC}		$V_{CC} = 5.5\text{ V}$,	$I_O = 0$, $V_I = V_{CC}$ or GND			3	μA
ΔI_{CC}^\ddagger	Control inputs	$V_{CC} = 5.5\text{ V}$,	One input at 3.4 V, Other inputs at V_{CC} or GND			2.5	mA
C_i	Control inputs	$V_I = 3\text{ V}$ or 0				6	pF
$C_{io}(\text{OFF})$		$V_O = 3\text{ V}$ or 0,	$\overline{OE} = V_{CC}$			6.5	pF
r_{on}^\S	$V_{CC} = 4\text{ V}$, TYP at $V_{CC} = 4\text{ V}$		$V_I = 2.4\text{ V}$, $I_I = 15\text{ mA}$			14	Ω
	$V_{CC} = 4.5\text{ V}$		$V_I = 0$, $I_I = 64\text{ mA}$			5	
			$I_I = 30\text{ mA}$			5	
			$V_I = 2.4\text{ V}$, $I_I = 15\text{ mA}$			10	

† All typical values are at $V_{CC} = 5\text{ V}$ (unless otherwise noted), $T_A = 25^\circ\text{C}$.

‡ This is the increase in supply current for each input that is at the specified TTL voltage level rather than V_{CC} or GND.

§ Measured by the voltage drop between the A and B terminals at the indicated current through the switch. On-state resistance is determined by the lowest voltage of the two (A or B) terminals.

switching characteristics over recommended operating free-air temperature range, $C_L = 50\text{ pF}$ (unless otherwise noted) (see Figure 1)

PARAMETER	FROM (INPUT)	TO (OUTPUT)	$V_{CC} = 4\text{ V}$		$V_{CC} = 5\text{ V}$ $\pm 0.5\text{ V}$		UNIT
			MIN	MAX	MIN	MAX	
t_{pd}^\parallel	A or B	B or A	0.35		0.25		ns
t_{en}	\overline{OE}	A or B	6.2		1.9	5.7	ns
t_{dis}	\overline{OE}	A or B	5.5		2.1	5.2	ns

¶ The propagation delay is the calculated RC time constant of the typical on-state resistance of the switch and the specified load capacitance, when driven by an ideal voltage source (zero output impedance).

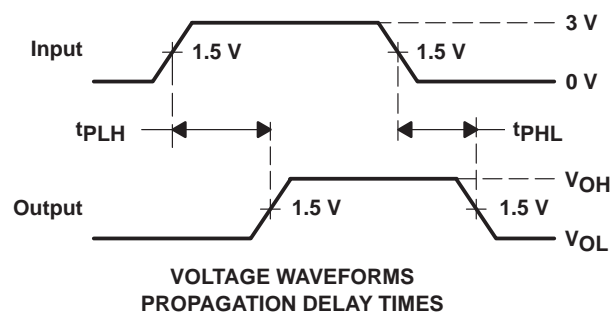
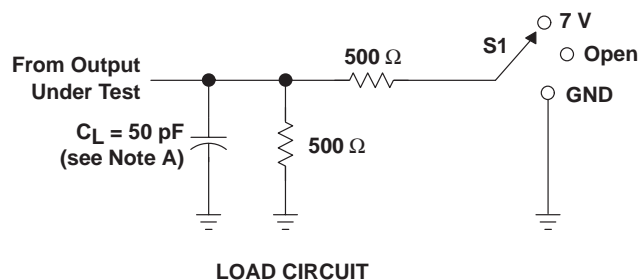
SN74CBTS3384

10-BIT FET BUS SWITCH

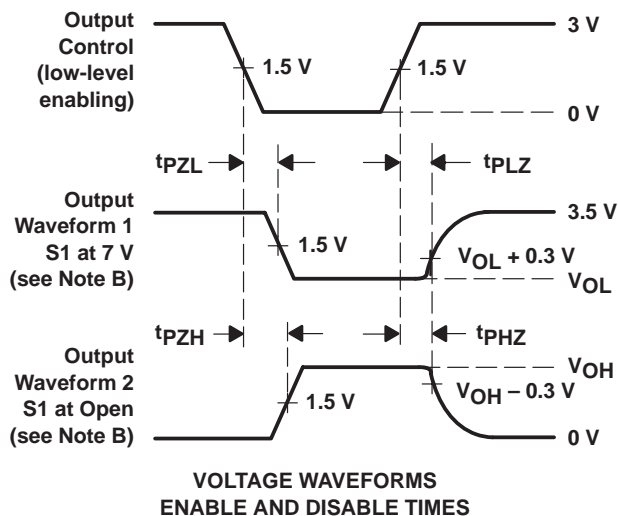
WITH SCHOTTKY DIODE CLAMPING

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PARAMETER MEASUREMENT INFORMATION



TEST	S1
t_{pd}	Open
t_{PLZ}/t_{PZL}	7 V
t_{PHZ}/t_{PHL}	Open



- NOTES:
- A. C_L includes probe and jig capacitance.
 - B. Waveform 1 is for an output with internal conditions such that the output is low except when disabled by the output control. Waveform 2 is for an output with internal conditions such that the output is high except when disabled by the output control.
 - C. All input pulses are supplied by generators having the following characteristics: $PRR \leq 10 \text{ MHz}$, $Z_O = 50 \Omega$, $t_r \leq 2.5 \text{ ns}$, $t_f \leq 2.5 \text{ ns}$.
 - D. The outputs are measured one at a time with one transition per measurement.
 - E. t_{PLZ} and t_{PHZ} are the same as t_{dis} .
 - F. t_{PZL} and t_{PZH} are the same as t_{en} .
 - G. t_{PLH} and t_{PHL} are the same as t_{pd} .

Figure 1. Load Circuit and Voltage Waveforms

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